

661.

标题: Terahertz current oscillations in a gated two-dimensional electron gas with antenna integrated at the channel ends

作者: Di Gaspare, A (Di Gaspare, Alessandra); Casini, R (Casini, Roberto); Foglietti, V (Foglietti, Vittorio); Giliberti, V (Giliberti, Valeria); Giovine, E (Giovine, Ennio); Ortolani, M (Ortolani, Michele)

来源出版物: APPLIED PHYSICS LETTERS 卷: 100 期: 20 文献号: 203504 DOI: 10.1063/1.4717464 出版年: MAY 14 2012

在 Web of Science 中的被引频次: 0

被引频次合计: 0

引用的参考文献数: 20

摘要: We studied terahertz current oscillations induced by a frequency-tunable radiation source in a AlGaAs/InGaAs/AlGaAs heterostructure field effect transistor channel. A planar antenna was integrated on-chip, and a substrate lens was used for broadband coupling of free-space radiation at 0.18-0.72 THz to the channel ends. Through spectral analysis of the detection signal, we identified two different mixing mechanisms: one related to channel current oscillations and the other to modulation of the gate-to-channel potential. Depending on gate bias and radiation frequency, the two mechanisms either compete or cooperate, leading to responsivity up to 300 V/W and noise equivalent power of 1 nW/Hz(0.5) (C) 2012 American Institute of Physics. [http://dx.doi.org/10.1063/1.4717464]

入藏号: WOS:000304265000088

语种: English

文献类型: Article

KeyWords Plus: FIELD-EFFECT TRANSISTORS; RADIATION; MIXER

地址: [Di Gaspare, Alessandra; Casini, Roberto; Foglietti, Vittorio; Giliberti, Valeria; Giovine, Ennio; Ortolani, Michele] CNR, Ist Foton & Nanotecnol, I-00156 Rome, Italy
[Giliberti, Valeria; Ortolani, Michele] Univ Roma La Sapienza, Dipartimento Fis, I-00185 Rome, Italy

通讯作者地址: Di Gaspare, A (通讯作者), CNR, Ist Foton & Nanotecnol, Via Cineto Romano 42, I-00156 Rome, Italy

电子邮件地址: michele.ortolani@ifn.cnr.it

出版商: AMER INST PHYSICS

出版商地址: CIRCULATION & FULFILLMENT DIV, 2 HUNTINGTON QUADRANGLE, STE 1 N O 1, MELVILLE, NY 11747-4501 USA

Web of Science 分类: Physics, Applied

学科类别: Physics

IDS 号: 945HZ

ISSN: 0003-6951

29 字符的来源出版物名称缩写: APPL PHYS LETT

ISO 来源出版物缩写: Appl. Phys. Lett.

来源出版物页码计数: 5